



东莞市华远电子有限公司

DONG GUAN SHI HUA YUAN ELECTRON CO.,LTD.

TEL: 86-769-5335378 86-769-5305266 FAX: 86-769-5316189

TO-92 Plastic-Encapsulate Transistors

2SD1616A

TRANSISTOR (NPN)

FEATURE

Power dissipation

P_{CM} : 0.75 W ($T_{amb}=25$)

Collector current

I_{CM} : 1 A

Collector-base voltage

$V_{(BR)CBO}$: 120 V

Operating and storage junction temperature range

T_J, T_{stg} : -55 to +150

TO—92

1.EMITTER

2. COLLECTOR

3. BSAE



ELECTRICAL CHARACTERISTICS ($T_{amb}=25$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 10 \mu A$, $I_E = 0$	120		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 2 mA$, $I_B = 0$	60		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 10 \mu A$, $I_C = 0$	6		V
Collector cut-off current	I_{CBO}	$V_{CB} = 60V$, $I_E = 0$		0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 6V$, $I_C = 0$		0.1	μA
DC current gain	h_{FE1}	$V_{CE} = 2V$, $I_C = 100mA$	135	600	
	h_{FE2}	$V_{CE} = 2V$, $I_C = 1A$	81		
Collector-emitter saturation voltage *	$V_{CE(sat)}$	$I_C = 1A$, $I_B = 50mA$		0.3	V
Base-emitter saturation voltage *	$V_{BE(sat)}$	$I_C = 1A$, $I_B = 50mA$		1.2	V
Base-emitter voltage *	V_{BE}	$V_{CE} = 2V$, $I_C = 50mA$		0.7	V
Transition frequency	f_T	$V_{CE} = 2V$, $I_C = 100mA$	100		MHz
Output capacitance	C_{ob}	$I_E = 0$, $f = 1MHz$		25	pF
Turn on time	t_{on}	$V_{CC} = 10V$, $I_C = 100mA$, $I_{B1} = -I_{B2} = 10mA$, $V_{BE(OFF)} = -2 \sim -3V$		0.07 typ	ms
Storage time	t_s			0.95 typ	ms
Fall time	t_F			0.07 typ	ms

*pulse test : $PW=350\mu S$, $d=2\%$ 。

CLASSIFICATION OF h_{FE1}

Rank	L	K	U
Range	135-270	200-400	300-600

Typical Characteristics

2SD1616A

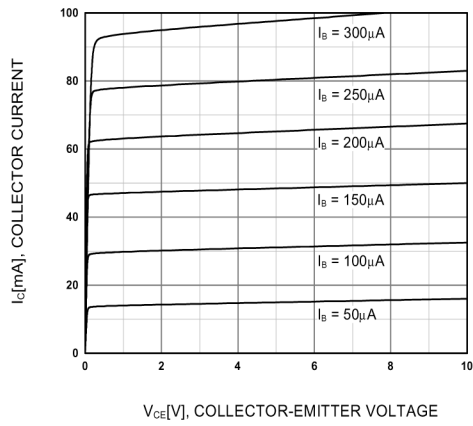


Figure 1. Static Characteristic

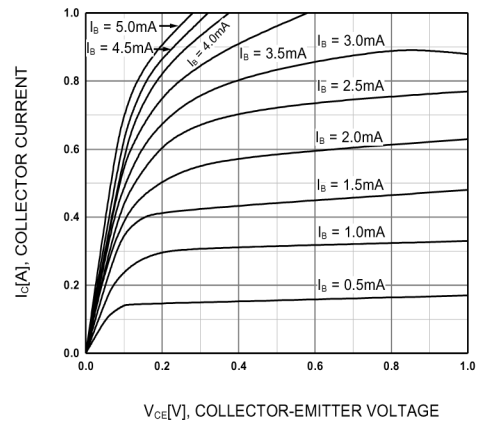


Figure 2. Static Characteristic

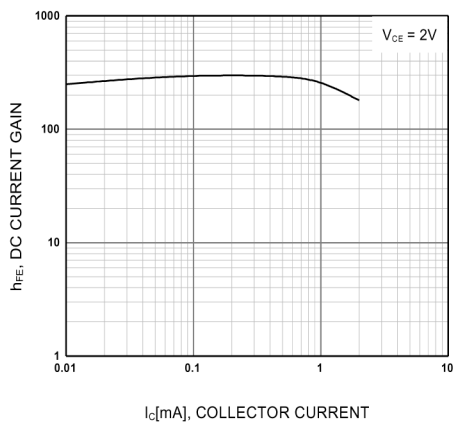


Figure 3. DC current Gain

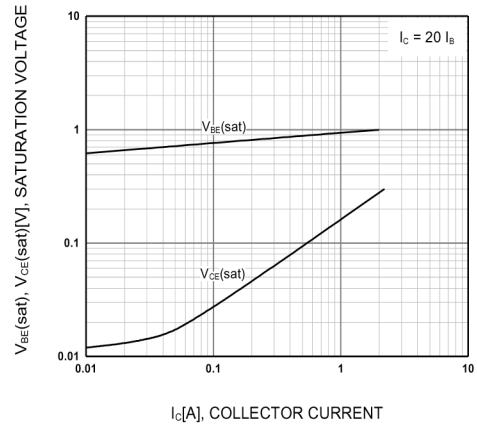


Figure 4. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

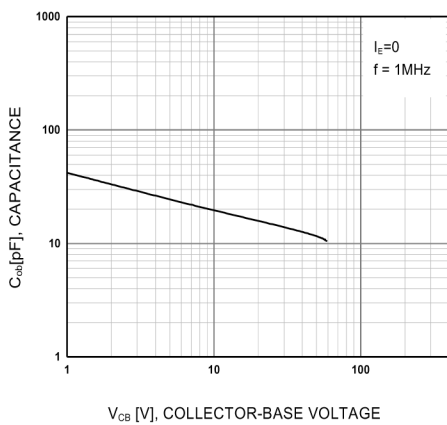


Figure 5. Collector Output Capacitance

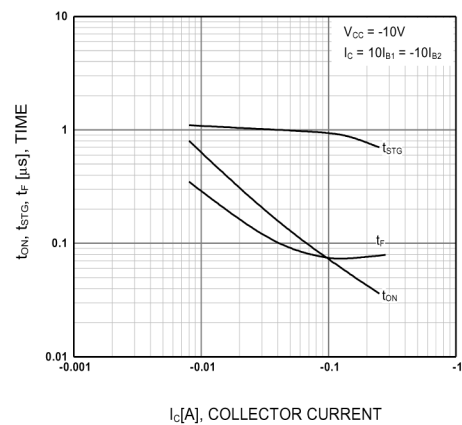


Figure 6. Switching Time

Typical Characteristics

2SD1616A

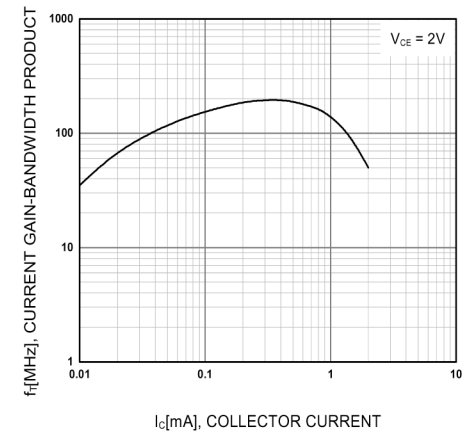


Figure 7. Current Gain Bandwidth Product

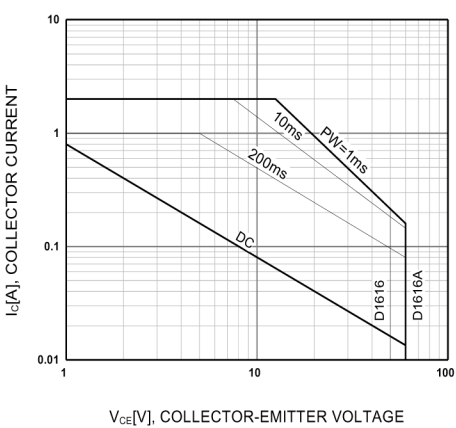


Figure 8. Safe Operating Area

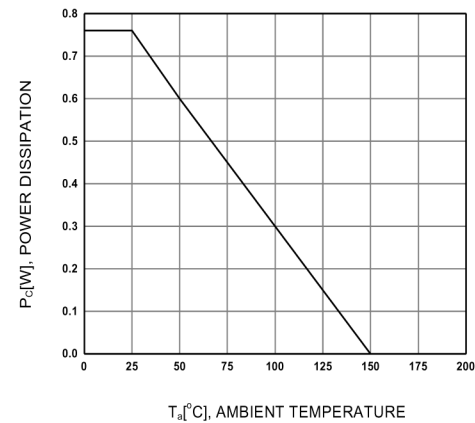
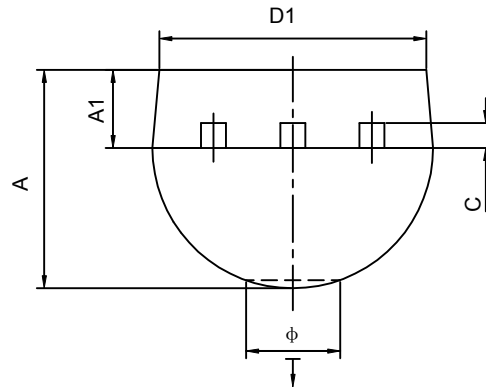
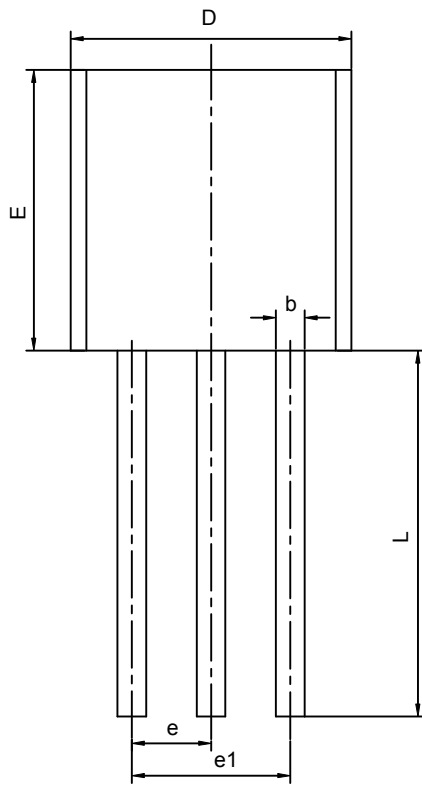


Figure 9. Power Derating

TO-92 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.400	4.700	0.173	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270TYP		0.050TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Ö		1.600		0.063
\downarrow	0.000	0.380	0.000	0.015